

Optical spectrum of bottom-up graphene nanoribbons: towards efficient atom-thick excitonic solar cells

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Recently, atomically well-defined cove-shaped graphene nanoribbons have been obtained using bottom-up synthesis. These nanoribbons have an optical gap in the visible range of the spectrum which make them candidates for donor materials in photovoltaic devices. From the atomistic point of view, their electronic and optical properties are not clearly understood. Therefore, in this work we carry out *ab-initio* density functional theory calculations combine with many-body perturbation formalism to study their electronic and optical properties. Through the comparison with experimental measurements, we show that an accurate description of the nanoribbon's optical properties requires the inclusion of electron-hole correlation effects. The energy, binding energy and the corresponding excitonic transitions involved are analyzed. We found that in contrast to zigzag graphene nanoribbons, the excitonic peaks in the absorption spectrum are a consequence of a group of transitions involving the first and second conduction and valence bands. Finally, we estimate some relevant optical properties that strengthen the potential of these nanoribbons for acting as a donor materials in photovoltaic.

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I. INTRODUCTION

The discovery of graphene and its unique electronic properties^{1,2} has led to a number proposals for novel electronic,³⁻⁵ optoelectronic,⁶ and photovoltaic⁷ devices. For instance, Bernardi *et al.*⁸ have recently proposed that graphene combined with transition metal dichalcogenides could yield high solar energy absorption rates - up to three orders of magnitude higher than the most efficient solar cells - paving the way for next-generation photovoltaics. Nevertheless, the lack of a band gap has hindered further development of graphene-only devices. Particularly in the case of photovoltaic applications, there are a number of key ingredients which are important in designing materials for harvesting solar energy. Besides the presence of a gap, which should preferably coincide with the visible spectrum range, the presence of Frenkel excitons (strongly bound excitons) is also important.⁹

There have been several attempts to induce such a band gap in graphene-like materials, including adsorbed atoms,^{10,11} strain engineering,^{12,13} doping,^{14,15} and lateral confinement.¹⁶⁻¹⁹ In particular, graphene nanoribbons (GNRs),^{16,17} laterally constrained graphene sheets, exhibit semiconducting behavior in narrow samples less than ten nanometers wide.²⁰ It has also been theoretically shown that the electronic properties of GNRs are strongly dependent on the edge geometry and width,²¹ which could be used to tune the band gap.²² Thus, using some features of GNRs, such as the semiconducting behavior and their quasi-1D character, which typically enhances the exciton binding energies,²³ one might envision employing them as long-exciton lifetime donor materials for photovoltaic applications.

However, tailoring GNRs by using top-down approaches, such as lithography,²⁴ unzipping of carbon

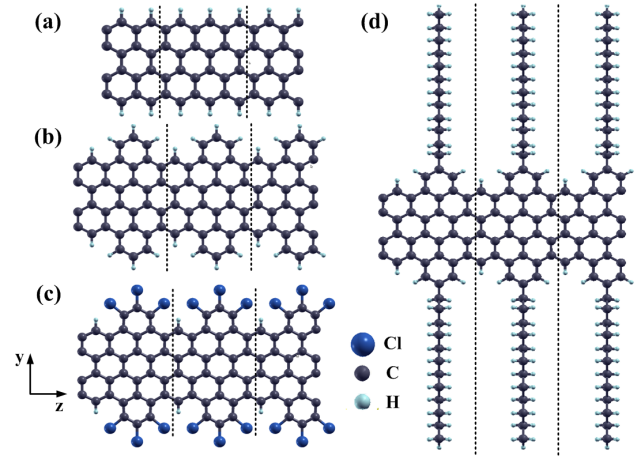


FIG. 1: Schematic representation of the four graphene nanoribbons studied. (a) 4-ZGNR, (b) H-CGNR, (c) Cl-CGNR, and (d) C₁₂H₂₅-CGNR. The vertical dotted lines indicates the length of the unit cell considered in the simulations. The periodic direction is along the z -axis.

nanotubes,²⁵ and sonification patterning²⁶ is still a challenging task, since these methods still lack the atomic precision control for tailoring the edge structure. Recently, bottom-up chemical synthesis has led to the accurate patterning of GNRs with atomically precise edges.²⁷ These synthesis methods generally use small appropriate polyphenylene molecules as precursors that can be mediated by either solutions²⁸⁻³¹ or metallic surfaces.³² More recently, Müllen's group reported solution-mediated synthesis of GNRs over 200 nm long and chemically precise widths of approximately 1 nm.^{29,30}

One of the resultant structures in the aforementioned studies (the so-called GNR 3) is composed of a 4-zigzag GNR with benzo-fused rings on both edges forming a

cove-shaped GNR (CGNR). These, subsequently, bond to either a chain of $C_{12}H_{25}$ ³⁰ or to Chlorine atoms²⁹ (see Fig. 1c and 1d). The authors show that, for both structures, the optical gap lie in the visible part of the spectrum, ranging from 1.7 to 1.9 eV, thus suggesting that this type of system could be used as a promising donor material for nanoscopic photovoltaic devices.²²

In order to better understand the electronic properties of these graphene nanoribbons, we carry out *ab-initio* density functional theory (DFT) calculations using the G_0W_0 correction to better describe the exchange and correlation potential. Subsequently we included electron-hole correlation effects via the Bethe-Salpeter equation (BSE) to simulate the optical spectrum. We elucidate the most important optical transitions as well as the exciton binding energies, comparing our results to recent experiments.^{29,30} Most importantly, we estimate the short-circuit current density for these atomically thin bottom-up GNRs, finding attractive values that go up to one order of magnitude higher than those estimated for a nanometer-thick Si and GaAs, two of the foremost systems used in photovoltaics, particularly as donor materials.

II. THEORY AND METHODOLOGY

We carry out this study considering four different GNRs whose widths are smaller than 1nm as shown in Figure 1. Although a pristine zig-zag nanoribbon has not been realized experimentally, the 4-zigzag GNR (4-ZGNR) in figure 1a is included as a reference for comparison purposes. It is considered in the lowest energy configuration, with antiferromagnetic order between carbon atoms of opposite edges, which induces a finite energy gap.³³ The two other structures (Fig. 1c and Fig 1d) correspond to those obtained experimentally, namely a 4-ZGNR with benzo-fused rings on either side terminated with either Chlorine (Cl-CGNR) atoms or a dodecane ($C_{12}H_{25}$ -CGNR) chain. Finally, in order to determine the effects of the side chains on the electronic structure we also performed calculations on a $C_{12}H_{25}$ -CGNR saturated only with hydrogen atoms, hereafter called H-CGNR.

The calculations were performed in three steps. First, plane-wave density functional theory^{34,35} is used to obtain the electronic ground-state by means of Perdew-Burke-Ernzerhof (PBE)³⁶ exchange-correlation functional currently implemented in the Quantum Espresso package.³⁷ We employed norm-conserving pseudopotentials and used a 90 Ry kinetic energy cutoff and a k-sampling grid in the Monkhorst-Pack scheme of $1 \times 1 \times 32$. The structures are fully optimized to their equilibrium position with forces smaller than 0.02 eV/Å. In all cases a supercell with a vacuum region of 16 Å in both directions perpendicular to the z axis was used. This is large enough to avoid spurious interactions between images.

Next, within the G_0W_0 approximation, the quasiparticle energies are obtained considering the Khom-Sham eigenstates and eigenvalues as a starting point,

$$E_n^{QP} = E_n^{KS} + \langle \Psi_n^{KS} | \Sigma(E_n^{QP}) - V_{XC} | \Psi_n^{KS} \rangle, \quad (1)$$

where V_{XC} , is the exchange correlation potential at the DFT level and Σ is the self-energy operator. The screened Coulomb potential W_0 is calculated within the Plasmon-Pole approach including 460 unoccupied bands. In addition, we used a truncated screened Coulomb interaction to avoid image effects between periodic cells.

Finally, the electron-hole interactions, relevant in photo-excitation processes, are included by solving the Bethe-Salpeter equation³⁸ for each excitonic state S

$$\sum_{v'c'\mathbf{k}'} \langle v\mathbf{c}\mathbf{k} | K^{eh} | v'c'\mathbf{k}' \rangle + (E_{\mathbf{c}\mathbf{k}}^{QP} - E_{v\mathbf{k}}^{QP}) A_{v\mathbf{c}\mathbf{k}}^S = \Omega^S A_{v\mathbf{c}\mathbf{k}}^S \quad (2)$$

where $A_{v\mathbf{c}\mathbf{k}}^S$, Ω^S is the exciton eigenfunction and eigenvalues for the S -th exciton respectively, and K^{eh} is the electron-hole interaction kernel. Together with the Tamm-Dancoff approximation,³⁹ eight valence bands and eight conduction bands are included to solve the BSE. Once the excitonic eigenvalues and eigenfunctions are obtained, one can calculate the optical absorption through the imaginary part of the dielectric function,

$$\epsilon_2(\omega) = 16\pi^2 e^2 / \omega^2 \sum_S |\mathbf{e} \cdot \langle 0 | \mathbf{v} | S \rangle|^2 \delta(\omega - \Omega^S) \quad (3)$$

where, \mathbf{v} corresponds to the velocity operator along the direction of the polarization of light \mathbf{e} , which is chosen parallel along the ribbon axis, since the significant optical response in 1D systems take place in this direction.⁴⁰ We stress that a finer k-grid sample of $1 \times 1 \times 128$ was used during the BSE procedure. The G_0W_0 and BSE calculations were performed using the BerkeleyGW package.⁴¹

III. RESULTS

A. Electronic Structure

Before going on to discuss the optical properties of the nanoribbons, we initially look at the electronic structure at the GGA level. It gives an insight to the character of the bands and the most important states contributing to the valence and conduction bands. As we will later see, these will not change with the inclusion of many-body corrections. Figure 2 shows the electronic band structure for all structures obtained using GGA. A direct comparison between the different panels shows the differences on the electronic structure of the 4-ZGNR (Fig. 2a) after the benzo-fused rings are added to the edges (Fig. 2(b-d)). Firstly, the valence band maximum (VBM), and conduction band minimum (CBM) are moved to the Γ point, and two of the topmost VBs and the bottommost CBs cross at approximately $k_z = \pi/3a$. In addition, the band

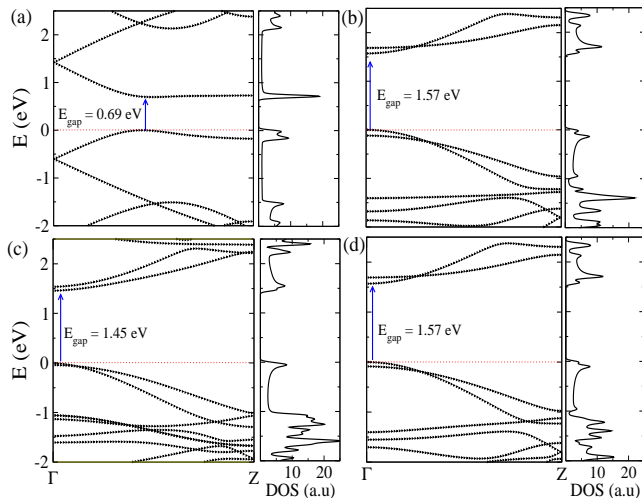


FIG. 2: Energy bands and its corresponding density of states calculated with GGA for: (a) 4-ZGNR, (b) H-CGNR, (c) Cl-CGNR, and (d) $C_{12}H_{25}$ -CGNR. The (blue) arrow indicates the energy gap. Since all the nanoribbons are semiconducting, the Fermi level was positioned at the top of the valence band.

gap is increased by approximately 1 eV and flat states arise in the energy interval from -1 to -2 eV.

By comparing the three cove-shaped we first notice that the $C_{12}H_{25}$ side chains have no significant effects on the dispersion relation of figure 2d in the energy window ranging from -1 to 2.5 eV compared to the hydrogen-saturated case. At the same time, when we substitute the H atoms by Chlorine there is a small reduction in the GGA band gap of approximately 0.1 eV. Most importantly the presence of Chlorine atoms brings the two valence bands closer together (making them almost degenerate) at the Γ point and inverts the two bottommost conduction bands.

To better understand the role of each atomic species in the electronic structure, we present the projected density of states (PDOS) for the four GNRs in Fig. 3. For the case of the 4ZGNR one notices the presence of localized states both at the top of the conduction band, and the bottom of the valence band. These can be associated with the well-known anti-ferromagnetic edges.⁴² That is not the case for the other nanoribbons, for which there is a similar balance between carbon states located at the edges and at the inner part. The PDOS also shows that Chlorine states give a contribution to both the CBM and the VBM. In addition, the C states assigned to the dodecane chain only come into play for energy values lower than -2.5 eV. This result combined with similarity in the band structure leads to the conclusion that they play no role in the optical properties of these systems. Thus, hereafter our predictions concerning the relevant optical transitions (those around the Fermi level) are carried out in the absence of the $C_{12}H_{25}$ chains.

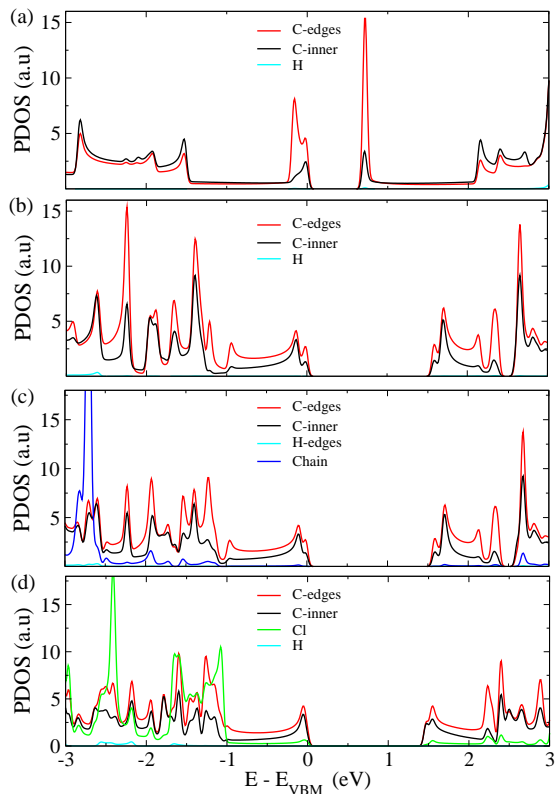


FIG. 3: Projected density of states for each atomic species at different spatial regions, calculated with GGA functional. The C-inner and chain states are related to the atoms located between the edges and those belonging to the $C_{12}H_{25}$ chain, respectively. From top to bottom: (a) 4-ZGNR, (b) H-CGNR, (c) $C_{12}H_{25}$ -CGNR, and (d) Cl-CGNR.

B. Optical properties

The GW-corrected quasiparticle band structures are shown in Fig. 4. For the sake of simplicity, the calculations for 4-ZGNR were performed in the unfolded Brillouin zone. The corrected band structures are very similar to the PBE ones, except by a rigid shift of the empty levels. As expected they all display larger values for the fundamental gap by at least twice the GGA one, as is indicated in Table I. This increase over the GGA gap is a signature of the key role that Coulomb interactions and reduced screening have over low-dimensional systems.⁴³

From the quasi-particle band structures one can obtain the non-interacting electron-hole optical transitions within GW-RPA, shown as red lines in the right panels of Fig. 4. These peaks are labeled as A^{ij} , indicating the interband transition from the i -th VB to the j -th CB.

For 4-ZGNR, the non-interacting optical spectrum presents 2 peaks. The first one (A^{11}) corresponds to a continuum of direct interband transitions between the VBM and CBM (ranging from 2.0 to 3.5 eV), which is

TABLE I: Energy band gap at different levels of theory (second to third columns). Fourth and fifth column show the theoretical and experimental values for the absorption maximum peak. Sixth to eleven-th column stands for the calculated binding energies for different excitonic states. The transitions where no exciton is found are left blank. All values are in eV.

	Band gap (eV)				Exciton binding energy (eV)					
	GGA	GW	BSE	Exp	E_1^{11}	E_2^{11}	E_3^{11}	E_1^{21}	E_1^{12}	E_1^{22}
4-ZGNR	0.69	2.02	0.8	-	1.22	0.87	0.5	1.49	1.41	-
H-CGNR	1.57	3.54	2.21	2.25 ^a	-	-	-	1.33	1.45	-
Cl-CGNR	1.45	3.39	2.11	2.09 ^b	1.37	-	-	-	-	1.28

^aRef. ³⁰ for C₁₂H₂₅-CGNR.

^bRef. ²⁹

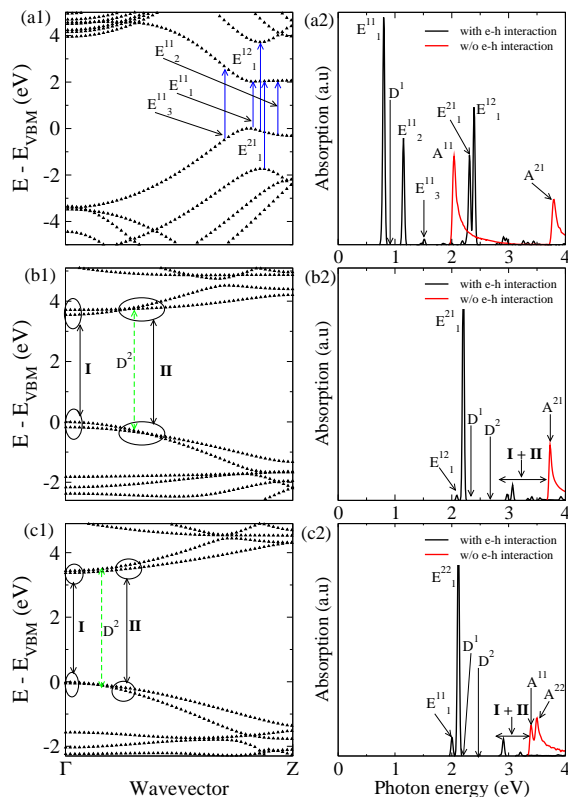


FIG. 4: Quasiparticle band structure (left) and optical absorption (right) for a) 4-ZGNR, b) H-CGNR, and c) Cl-CGNR. A^{ij} corresponds to the absorption at the level of GW-RPA from the i^{th} VB to the j^{th} CB, and E_S^{ij} is associated to the corresponding S^{th} exciton for that transition including e-h interaction. (a1) The solid (blue) arrow stands for the wavevector values (or region of values) at which the excitonic transition occurs. (b1) and (c1) The green dash-dotted arrow indicates the position in the k-space at which the dark exciton D^2 takes place. The absorption curves were calculated with an artificial gaussian broadening of 15 meV.

followed by another continuum of peaks (starting at 3.8 eV) that correspond to interchanged transitions between the second valence band and the first conduction band.⁵⁵

For H-CGNR the direct transition from the CBM to the VBM is forbidden. The first observed transition occurs from VBM to the CBM+1. On the other hand, the non-interacting electron-hole optical spectrum for Cl-CGNR presents two peaks at $A^{11}=3.39$ and $A^{22}=3.49$ which corresponds to direct transitions around the Γ point. This means that the interchanged conduction bands at the Γ point leads to a different set of transitions. This can be understood from the symmetry of the wavefunctions (Figure S5 of the supplementary information).

In the presence of electron-hole interactions, bright (E_S^{ij}) and dark (D^S) excitonic states arise in the absorption spectrum. by means of the exciton amplitude of probability, we are able to elucidate the weight associated to each transition. Based on this weight, we indexed each exciton state peak (black lines in the right panels of Figure 4) to the most probable optical transition taking place. The different VBs and CBs involved in those transitions are presented in table S3. We also calculated the excitation binding energies and the results are shown in table I.

The first continuum of transitions for the pristine GNR gives rise to intense peaks related to bright bound excitonic states located at $E_1^{11}=0.8$ eV and $E_2^{11}=1.15$ eV. In addition, resonant excitons (E_1^{21} and E_1^{12}), whose excitation energies lie above the quasiparticle band gap, also present intense peaks in the absorption spectrum. These resonant states present binding energies higher than the first bound ones as can be seen in Table I. We also mention that for energies below 1.5 eV, two Dark excitons (not all of them shown) are identified in the absorption spectrum (see supplementary information). Energywise, each dark exciton arises in the vicinity of the bright ones. For instance, the first dark exciton, $D^1=0.84$ eV, is only 40 meV higher than the bright exciton E_1^{11} . A similar behavior has been previously observed in 8-ZGNR.⁴⁴

The e-h optical spectrum for the two CGNR comes from a more complex scenario, since there are many

bands around the Fermi level. Thus, the excitonic peaks do not belong to a well-defined interband transition. For instance, the first peak in the H-CG NR absorption spectrum, $E_1^{12} = 2.09$ eV, and the second peak (the most intense one) $E_1^{21} = 2.21$ eV, arise from a group of transitions taking place at the Γ point. As previously mentioned they are indexed following the largest contribution to the exciton wavefunction, but in fact, they involve combinations of transitions between the two highest valence bands and the two lowest conduction bands. This includes the originally forbidden direct transitions.

Accordingly, for Cl-CG NR, in the presence of electron-hole interaction, the exciton states $E_1^{11}=2.0$ and $E_1^{22}=2.11$ arise from a similar combination involving the two topmost VBs and the bottommost CBs around the Γ point. It should be pointed out that differently to the H-CG NR case, the presence of Chlorine gives rise to larger weights in the direct optical transition from the VBM to the CBM.

In both CNRs, there is also a set of less intense peaks in the energy range from 2.9 - 3.7 eV. These peaks correspond to groups of transitions I and II (shown in the left panel of Figure 4), which occur at different wavevectors in two distinct regions, namely close to the Γ point and around $k_z = \pi/3a$. It is worth mentioning that such optical transitions corresponding to groups of bands have not been observed before either in armchair GNRs or Chrevoon-type GNRs.^{23,45,46} This behavior, however, has been previously predicted in silicon nanowires⁴⁷ and is a consequence of the proximity between many quasi-particle energy levels at specific wavevectors.

In order to explore the possible use of bottom-up GNRs for photovoltaic applications the absorbance

$$A(\omega) = 1 - e^{-\alpha(\omega)\Delta L} \quad (4)$$

was calculated. Here $\alpha(\omega) = \omega\epsilon_2(\omega)/cn$ is the absorption coefficient whose values for the GNRs in this work go up to $5 \times 10^5 \text{ cm}^{-1}$ (see supplementary information). Here c , n and ΔL are the speed of light, refractive index and the dimension of the simulation cell in the layer-perpendicular direction respectively. The refractive index is assumed to be unity since the unit cell is constituted mainly by vacuum as described in Ref.⁸. In the inset of Fig. 5, we compare the theoretical e-h absorbance with the experimental measurements obtained by Narita *et al.*³⁰ and Tan *et al.*²⁹ One can note that the position of the peaks are in good agreement with our calculations. This quantitative agreement between theory and experiment strengthen the crucial role electron-hole interactions have in predicting accurate optical properties.

Figure 5 depicts the absorbance of the three GNRs as well as the spectral irradiance of the incident AM1.5 solar spectrum (orange line) for comparison.⁴⁸ Both the Cl-CG NR and H-CG NR show absorbances (related to one peak) ranging from 0.5-7%. In contrast, 4-ZG NR, presents three intense peaks with absorbance values that go up to 6.5% and spreads over the entire visible and near infrared electromagnetic spectrum. The peaks in

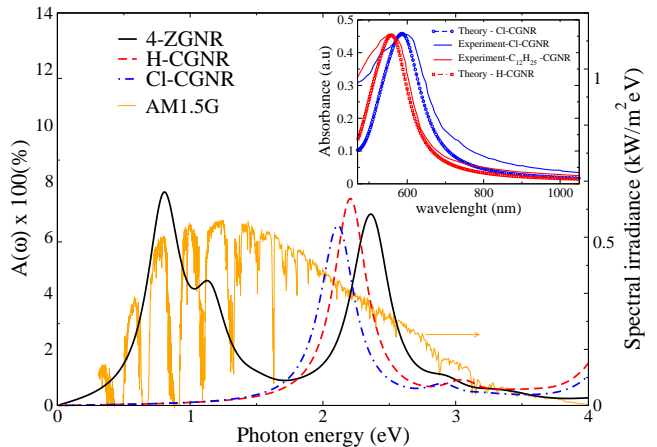


FIG. 5: Absorbance as a function of the photon energy for three different GNRs. The AM1.5 Global irradiance is overlaid to indicate the regions in energy of maximum photon incidence. Inset: Absorbance as a function of photon wavelength in arbitrary units. The experimental curves were extracted from Ref.³⁰ and²⁹. For all theoretical results an artificial Gaussian broadening of 0.15 eV was used.

the absorbance have a one-to-one correspondence with the energy of the excitons shown in Figure 4. We note that the absorption coefficients have the same order of magnitude as in graphene oxide,⁴⁹ and one order of magnitude higher than in bulk GaAs⁵⁰ and P3HT⁵¹, two of the foremost materials used in photovoltaics due to their high power conversion efficiencies. Furthermore, these values double the 2.3% sun light absorption reached for graphene in the visible spectrum⁵² and are comparable with the one of monolayer MoS₂⁵³, a very promising visible light absorber.

We then estimate the upper limit for the short-circuit current density related to a donor material in a photovoltaic device,

$$J_{SC} = e \int_{E_{gap}/\hbar}^{\infty} A(\omega) I_{ph}(\omega) d\omega, \quad (5)$$

where $I_{ph}(\omega)$ is the photon spectral irradiance of the source and e is the electron charge.

The short-circuit current densities for 4-ZG NR, H-CG NR and Cl-CG NR are calculated to be 1.48, 0.54 and 0.51 mA/cm^2 , respectively. These values are already up to 1 order of magnitude larger than nanometer-thick silicon.⁸ The value for 4-ZG NR is almost three times that of the H(Cl)-CG NR since its absorbance covers the energy regions around 1.1 eV. According to the Shockley-Queisser limit this would provide the most efficient photovoltaic device.⁵⁴ Thus, although pristine GNRs have not been realized, they seem to provide an upper limit for the short-circuit current and absorbance in graphene nanoribbons. Nevertheless, the position of the main peak lies below that value and bringing it to higher energies requires a strategy to further increase the optical gap.

This would be hard as the width of the nanoribbon is already at its limit.

The cove-shaped GNRs, on the other hand, already give significant improvement over graphene. The first exciton also has a higher binding energy compared to the pristine case, but most importantly its position lies in the high energy end of the solar spectrum. Consequently one could use wider molecular precursors to decrease the optical gap and bring the transitions closer to the energy where efficiency is a maximum.

IV. CONCLUSIONS

We have carried out DFT calculations combined with many-body perturbation theory to study the electronic and optical properties of novel atomically well-defined graphene nanoribbons. Through the comparison with experimental measurements, we were able to show that an accurate description of the GNR's optical properties involves the inclusion of electron-hole correlation effects.

We also found that the excitonic peaks in the absorption spectrum of cove-shaped graphene nanoribbons are

consequence of a group of transitions involving the first and second conduction and valence bands. We also note that different functionalization of the edges can lead to changes in the character of the band transitions.

Finally, we estimated the short-circuit current density for the nanometer thick bottom-up GNRs, finding attractive values that go up to one order of magnitude higher than those estimated for a nanometer-thick Si and GaAs, foremost materials used in photovoltaic. These interesting results show the possibility of use bottom-up GNRs as promising donor materials in photovoltaics. In particular, we propose that cove-shaped GNRs could be assembled using wider precursor molecules to tailor the optical gap, thus enhancing even further their potential for photovoltaics

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